HD74HC279

Quad. \overline{S} - \overline{R} Latches

HITACHI

Description

The latch is ideally suited for use as temporary stage for binary information processing and input/output units. When either \overline{S} or \overline{R} is low, output is dependent on \overline{R} input. When both inputs are high, Output is stored before the indicated steady-state input conditions were established. And when both inputs are low, output is high, but this high level are uncontinuance, if either of input goes high.

Features

• High Speed Operation: t_{pd} (\overline{S} to Q) = 10 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 10 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 2$ to 6 V

• Low Input Current: 1 µA max

• Low Quiescent Supply Current: I_{CC} (static) = 2 μ A max (Ta = 25°C)

Function Table

Input		Output	
<u>\$</u> *2	R	Q	
Н	Н	$Q_{_{0}}$	
L	Н	Н	
Н	L	L	
L	L	H*1	

H: High level L: Low level

 ${\bf Q}_{\scriptscriptstyle 0}$: The level of Q respectively, before the indicated steady-state input conditions were established.

Notes: 1. It is unpredictable, if \overline{S} or \overline{R} goes High.

2. As to latches which has two \overline{S} inputs.

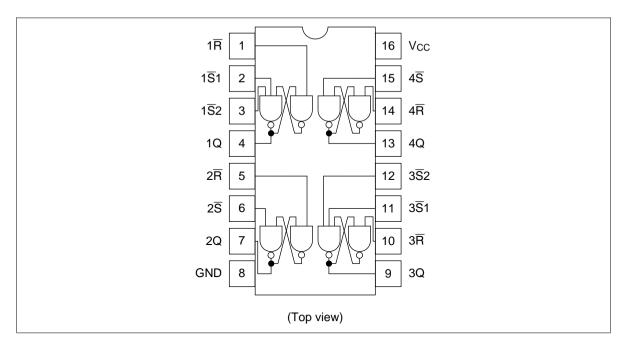
H: Both of \overline{S} inputs are high.

L: Either or both of \overline{S} inputs are low.

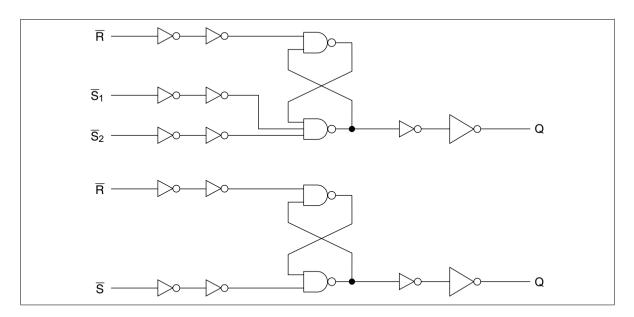


HD74HC279

Pin Arrangement



Logic Diagram (1/2)



DC Characteristics

			Ta =	: 25°(3	Ta = - +85°C	–40 to	_		
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions	s
Input voltage	V _{IH}	2.0	1.5	_	_	1.5	_	V		
		4.5	3.15	_	_	3.15	_	_		
		6.0	4.2	_	_	4.2	_	-		
	V _{IL}	2.0	_	_	0.5	_	0.5	V		
		4.5	_	_	1.35	_	1.35	=		
		6.0	_	_	1.8	_	1.8	_		
Output voltage	V_{OH}	2.0	1.9	2.0	_	1.9	_	V	Vin = V _{IH} or V _{IL}	$I_{OH} = -20 \mu A$
		4.5	4.4	4.5	_	4.4	_	=		
		6.0	5.9	6.0	_	5.9	_	_		
		4.5	4.18	_	_	4.13	_	-	-	I _{OH} = -4 mA
		6.0	5.68	_	_	5.63	_	-		$I_{OH} = -5.2 \text{ mA}$
	V _{OL}	2.0	_	0.0	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	Ι _{οL} = 20 μΑ
		4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	-		
		4.5	_	_	0.26	_	0.33	=		I _{OL} = 4 mA
		6.0	_	_	0.26	_	0.33	_		I _{OL} = 5.2 mA
Input current	lin	6.0	_	_	±0.1	_	±1.0	μΑ	Vin = V _{CC} or GN	D
Quiescent supply current	I _{cc}	6.0	_	_	2.0	_	20	μΑ	Vin = V _{CC} or GN	D, lout = 0 μA

HD74HC279

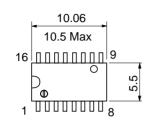
AC Characteristics ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

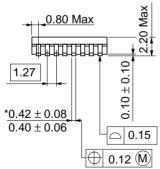
	Ta = -40 to
Ta = 25°C	+85°C

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Propagation delay	t _{PLH}	2.0	_	_	130	_	165	ns	S̄ to Q
time	$t_{\tiny PHL}$	4.5	_	10	26	_	33	_	
		6.0	_	_	22	_	28	_	
	t _{PHL}	2.0	_	_	120	_	150	ns	R to Q
		4.5	_	12	24	_	30	_	
		6.0	_	_	20	_	26	=	
Output rise/fall	t _{TLH}	2.0	_	_	75	_	95	ns	
time	t_{THL}	4.5	_	5	15	_	19	=	
		6.0	_	_	13	_	16	_	
Input capacitance	Cin	_	_	5	10	_	10	pF	

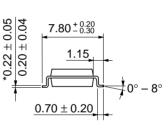
Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min $0.25^{+0.13}_{-0.05}$ 0.48 ± 0.10 2.54 ± 0.25 $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm





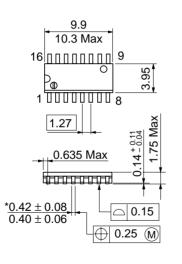


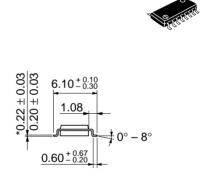


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 a

*Dimension including the plating thickness
Base material dimension

Unit: mm

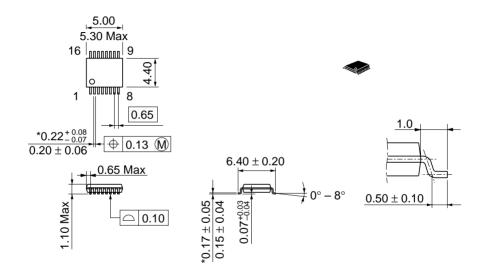




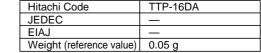
*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Unit: mm



*Dimension including the plating thickness
Base material dimension



Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HTACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

http:semiconductor.hitachi.com/

NorthAmerica URL Europe Asia (Singapore)

http://www.hitachi-eu.com/hel/ecg http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD_Frame.htm Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm

http://www.hitachi.co.jp/Sicd/indx.htm Japan

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui,

Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

Copyright ' Hitachi, Ltd., 1999. All rights reserved. Printed in Japan.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.